

FEATURES

- 44V Supply Maximum Rating**
- V_{SS} to V_{DD} Analog Signal Range**
- Single/Dual Supply Specifications**
- Wide Supply Ranges (10.8V to 16.5V)**
- Extended Plastic Temperature Range (-40°C to +85°C)**
- Low Power Dissipation (28mW max)**
- Low Leakage (20pA typ)**
- Superior Alternative to:
DG508A, HI-508
DG509A, HI-509**

PMI	ADI	SILICONIX	MAXIM	HARRIS
Order P/N Below	Equivalent P/N			
PMADG508AKN	ADG508AKN	DG508ACJ	DG508ACJ	HI3-0508-5
PMADG508ABQ	ADG508ABQ	DG508ABK	DG508ABK	HI1-0508-4
PMADG508AKP	ADG508AKP			HI4P0508-5
PMADG508AKR	ADG508AKR	DG508ADY		
PMADG508ATE	ADG508ATE	DG508AAZ		
PMADG508ATE/883	ADG508ATE/883	DG508AAZ/883		HI4-0508/883
PMADG508ATQ	ADG508ATQ	DG508AAK	DG508AAK	HI1-0508-2
PMADG508ATQ/883	ADG508ATQ/883	DG508AAZ/883	DG508AAZ/883	HI1-0508/883
PMADG509AKN	ADG509AKN	DG509ACJ	DG509ACJ	HI3-0509-5
PMADG509ABQ	ADG509ABQ	DG509ABK	DG509ABK	HI1-0509-4
PMADG509AKP	ADG509AKP			HI4P0509-5
PMADG509AKR	ADG509AKR	DG509ADY		
PMADG509ATE	ADG509ATE	DG509AAZ		
PMADG509ATE/883	ADG509ATE/883	DG509AAZ/883		HI4-0509/883
PMADG509ATQ	ADG509ATQ	DG509AAK	DG509AAK	HI1-0509-2
PMADG509ATQ/883	ADG509ATQ/883	DG509AAK/883	DG509AAK/883	HI1-0509/883

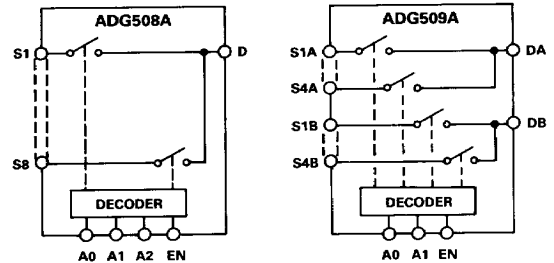
GENERAL DESCRIPTION

The ADG508A and ADG509A are CMOS monolithic analog multiplexers with 8 channels and dual 4 channels respectively. The ADG508A switches one of 8 inputs to a common output depending on the state of three binary addresses and an enable input. The ADG509A switches one of 4 differential inputs to a common differential output depending on the state of two binary addresses and an enable input. Both devices have TTL and 5V CMOS logic compatible digital inputs.

The ADG508A and ADG509A are designed on an enhanced LC²MOS process which gives an increased signal capability of V_{SS} to V_{DD} and enables operation over a wide range of supply voltages. The devices can comfortably operate anywhere in the 10.8V to 16.5V single or dual supply range. These multiplexers also feature high switching speeds and low R_{ON}.

PRODUCT HIGHLIGHTS

1. **Single/Dual Supply Specifications with a Wide Tolerance:**
The devices are specified in the 10.8V to 16.5V range for both single and dual supplies.
2. **Extended Signal Range:**
The enhanced LC²MOS processing results in a high breakdown and an increased analog signal range of V_{SS} to V_{DD}.
3. **Break-Before-Make Switching:**
Switches are guaranteed break-before-make so that input signals are protected against momentary shorting.
4. **Low Leakage:**
Leakage currents in the range of 20pA make these multiplexers suitable for high precision circuits.



Functional Block Diagrams

ORDERING INFORMATION¹

Temperature Range and Package		
-40°C to +85°C	-40°C to +85°C	-55°C to +125°C
Plastic DIP ADG508AKN ADG509AKN	Hermetic ADG508ABQ ADG509ABQ	Hermetic ADG508ATQ ADG509ATQ
PLCC² ADG508AKP ADG509AKP		LCCC³ ADG508ATE ADG509ATE

NOTES

- ¹To order MIL-STD-883, Class B processed parts, add /883B to part number. Contact your local sales office for military data sheet.
- ²PLCC: Plastic Leaded Chip Carrier.
- ³LCCC: Leadless Ceramic Chip Carrier.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices.

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
Tel: 617/329-4700 Fax: 617/326-8703 Twx: 710/394-6577
Telex: 924491 Cable: ANALOG NORWOODMASS

SPECIFICATIONS

Dual Supply ($V_{DD} = +10.8V$ to $+16.5V$, $V_{SS} = -10.8V$ to $-16.5V$ unless otherwise noted)

Parameter	ADG508A ADG509A K Version		ADG508A ADG509A B Version		ADG508A ADG509A T Version		Units	Comments
	+25°C	-40°C to +85°C	25°C	-40°C to +85°C	+25°C	-55°C to +125°C		
ANALOG SWITCH								
Analog Signal Range	V_{SS} V_{DD}	V_{SS} V_{DD}	V_{SS} V_{DD}	V_{SS} V_{DD}	V_{SS} V_{DD}	V_{SS} V_{DD}	V min V max	
R_{ON}	280 450 300	600 400	280 450 300	600 400	280 450 300	600 400	Ω typ Ω max Ω max	-10V \leq V_S \leq +10V, $I_{DS} = 1mA$; Test Circuit 1 $V_{DD} = 15V(\pm 10\%)$, $V_{SS} = -15V(\pm 10\%)$ $V_{DD} = 15V(\pm 5\%)$, $V_{SS} = -15V(\pm 5\%)$ $V_S = 0$, $I_{DS} = 1mA$
R_{ON} Drift	0.6		0.6		0.6		%/°C typ	
R_{ON} Match	5		5		5		% typ	-10V \leq V_S \leq +10V, $I_{DS} = 1mA$
I_S (OFF), Off Input Leakage	0.02 1	50	0.02 1	50	0.02 1	50	nA typ nA max	$V_1 = \pm 10V$, $V_2 = \mp 10V$; Test Circuit 2
I_D (OFF), Off Output Leakage	0.04 1	100	0.04 1	100	0.04 1	100	nA typ nA max	$V_1 = \pm 10V$, $V_2 = \mp 10V$; Test Circuit 3
ADG508A	1	50	1	50	1	50	nA max	
ADG509A	1	50	1	50	1	50	nA max	
I_D (ON), On Channel Leakage	0.04 1	100	0.04 1	100	0.04 1	100	nA typ nA max	$V_1 = \pm 10V$, $V_2 = \mp 10V$; Test Circuit 4
ADG508A	1	100	1	100	1	100	nA max	
ADG509A	1	50	1	50	1	50	nA max	
I_{DIFF} , Differential Off Output Leakage (ADG509A only)		25		25		25	nA max	$V_1 = \pm 10V$, $V_2 = \mp 10V$; Test Circuit 5.
DIGITAL CONTROL								
V_{INH} , Input High Voltage		2.4		2.4		2.4	V min	
V_{INL} , Input Low Voltage		0.8		0.8		0.8	V max	
I_{INL} or I_{INH}		1		1		1	μA max	$V_{IN} = 0$ to V_{DD}
C_{IN} Digital Input Capacitance	8		8		8		pF max	
DYNAMIC CHARACTERISTICS								
$t_{TRANSITION}^1$	200 300	400	200 300	400	200 300	400	ns typ ns max	$V_1 = \pm 10V$, $V_2 = \mp 10V$; Test Circuit 6
t_{OPEN}^1	50 25	10	50 25	10	50 25	10	ns typ ns min	Test Circuit 7
$t_{ON}(EN)^1$	200 300	400	200 300	400	200 300	400	ns typ ns max	Test Circuit 8
$t_{OFF}(EN)^1$	200 300	400	200 300	400	200 300	400	ns typ ns max	Test Circuit 8
OFF Isolation	68 50		68 50		68 50		dB typ dB min	$V_{EN} = 0.8V$, $R_L = 1k\Omega$, $C_L = 15pF$, $V_S = 7V_{rms}$, $f = 100kHz$
C_S (OFF)	5		5		5		pF typ	$V_{EN} = 0.8V$
C_D (OFF)								
ADG508A	22		22		22		pF typ	$V_{EN} = 0.8V$
ADG509A	11		11		11		pF typ	
Q_{INJ} , Charge Injection	4		4		4		pC typ	$R_S = 0\Omega$, $V_S = 0V$; Test Circuit 9
POWER SUPPLY								
I_{DD}	0.6	1.5	0.6	1.5	0.6	1.5	mA typ mA max	$V_{IN} = V_{INL}$ or V_{INH}
I_{SS}	20	0.2	20	0.2	20	0.2	μA typ mA max	$V_{IN} = V_{INL}$ or V_{INH}
Power Dissipation	10	28	10	28	10	28	mW typ mW max	

NOTE

¹Sample tested at 25°C to ensure compliance.
Specifications subject to change without notice.

Single Supply ($V_{DD} = +10.8V$ to $+16.5V$, $V_{SS} = GND = 0V$ unless otherwise noted)

Parameter	ADG508A ADG509A K Version		ADG508A ADG509A B Version		ADG508A ADG509A T Version		Units	Comments
	+25°C	-40°C to +85°C	+25°C	-40°C to +85°C	+25°C	-55°C to +125°C		
ANALOG SWITCH								
Analogue Signal Range	GND	GND	GND	GND	GND	GND	V min	GND ≤ V _S ≤ +10V, I _{DS} = 0.5mA; Test Circuit 1
R _{ON}	V _{DD} 500	V _{DD} 1000	V _{DD} 500	V _{DD} 1000	V _{DD} 500	V _{DD} 1000	V max	
R _{ON} Drift	700	1000	700	1000	700	1000	Ω typ	
R _{ON} Match	0.6		0.6		0.6		Ω max	
	5		5		5		%/°C typ	
I _S (OFF), Off Input Leakage	0.02		0.02		0.02		nA typ	V ₁ = +10V/GND, V ₂ = GND/+10V; Test Circuit 2
	1	50	1	50	1	50	nA max	
I _D (OFF), Off Output Leakage	0.04		0.04		0.04		nA typ	V ₁ = +10V/GND, V ₂ = GND/+10V; Test Circuit 3
ADG508A	1	100	1	100	1	100	nA max	
ADG509A	1	50	1	50	1	50	nA max	
I _D (ON), On Channel Leakage	0.04		0.04		0.04		nA typ	V ₁ = +10V/GND, V ₂ = GND/+10V; Test Circuit 4
ADG508A	1	100	1	100	1	100	nA max	
ADG509A	1	50	1	50	1	50	nA max	
I _{DIFF} , Differential Off Output Leakage (ADG509A only)		25		25		25	nA max	V ₁ = +10V/GND, V ₂ = GND/+10V; Test Circuit 5.
DIGITAL CONTROL								
V _{INH} , Input High Voltage		2.4		2.4		2.4	V min	V _{IN} = 0 to V _{DD}
V _{INL} , Input Low Voltage		0.8		0.8		0.8	V max	
I _{INL} or I _{INH}		1		1		1	μA max	
C _{IN} Digital Input Capacitance	8		8		8		pF max	
DYNAMIC CHARACTERISTICS								
t _{TRANSITION} ¹	300		300		300		ns typ	V ₁ = +10V/GND, V ₂ = GND/+10V; Test Circuit 6
	450	600	450	600	450	600	ns max	
t _{OPEN} ¹	50		50		50		ns typ	Test Circuit 7
	25	10	25	10	25	10	ns min	
t _{ON} (EN) ¹	250		250		250		ns typ	Test Circuit 8
	450	600	450	600	450	600	ns max	
t _{OFF} (EN) ¹	250		250		250		ns typ	Test Circuit 8
	450	600	450	600	450	600	ns max	
OFF Isolation	68		68		68		dB typ	V _{EN} = 0.8V, R _L = 1kΩ, C _L = 15pF, V _S = 3.5V rms, f = 100kHz
	50		50		50		dB min	
C _S (OFF)	5		5		5		pF typ	V _{EN} = 0.8V
C _D (OFF)								
ADG508A	22		22		22		pF typ	V _{EN} = 0.8V
ADG509A	11		11		11		pF typ	
Q _{INJ} , Charge Injection	4		4		4		pC typ	R _S = 0Ω, V _S = 0V; Test Circuit 9
POWER SUPPLY								
I _{DD}	0.6		0.6		0.6		mA typ	V _{IN} = V _{INL} or V _{INH}
		1.5		1.5		1.5	mA max	
Power Dissipation	10		10		10		mW typ	
		25		25		25	mW max	

NOTE
¹Sample tested at 25°C to ensure compliance.
 Specifications subject to change without notice.

TRUTH TABLES

A2	A1	A0	EN	ON SWITCH
X	X	X	0	NONE
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

X = Don't Care **ADG508A**

A1	A0	EN	ON SWITCH PAIR
X	X	0	NONE
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

X = Don't Care **ADG509A**

ABSOLUTE MAXIMUM RATINGS*

(T_A = 25°C unless otherwise noted)

V _{DD} to V _{SS}	44V
V _{DD} to GND	25V
V _{SS} to GND	-25V
Analog Inputs¹	
Voltage at S, D	V _{SS} -2V to V _{DD} +2V or 20mA, Whichever Occurs First
Continuous Current, S or D	20mA
Pulsed Current S or D	
1ms Duration, 10% Duty Cycle	40mA

Digital Inputs¹

Voltage at A, EN V_{SS} -4V to V_{DD} +4V or 20mA, Whichever Occurs First

Power Dissipation (Any Package)

Up to +75°C 470mW
Derates above +75°C by 6mW/°C

Operating Temperature

Commercial (K Version) -40°C to +85°C
Industrial (B Version) -40°C to +85°C
Extended (T Version) -55°C to +125°C
Storage Temperature Range -65°C to +150°C

NOTE

¹Overtolerance at A, EN, S or D will be clamped by diodes. Current should be limited to the Maximum Rating above.

*COMMENT: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

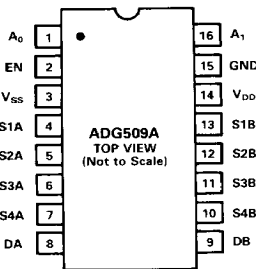
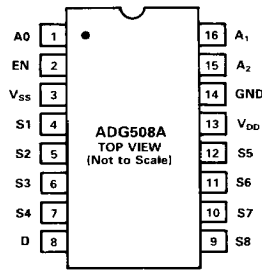
CAUTION

ESD (Electro-Static-Discharge) sensitive device. The digital control inputs are diode protected; however, permanent damage may occur on unconnected devices subject to high energy electrostatic fields. Unused devices must be stored in conductive foam or shunts. The protective foam should be discharged to the destination socket before devices are removed.

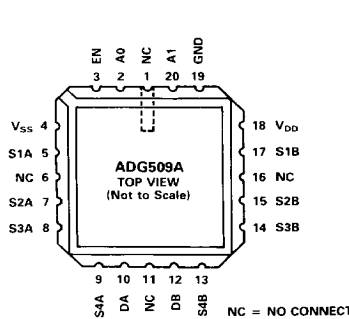
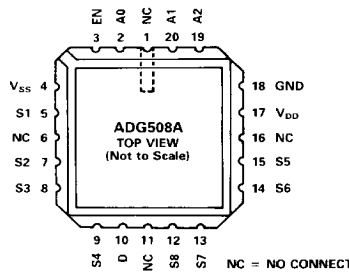


PIN CONFIGURATIONS

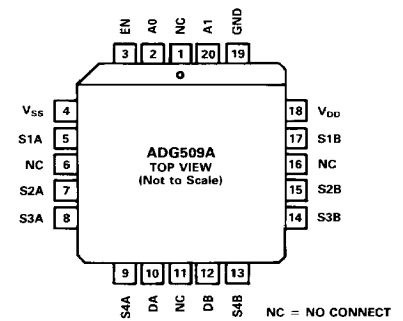
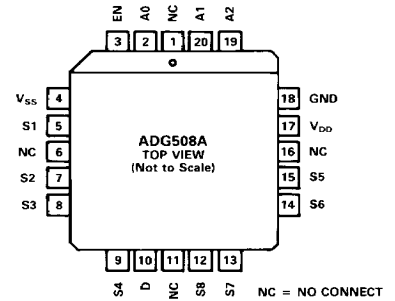
DIP



LCCC

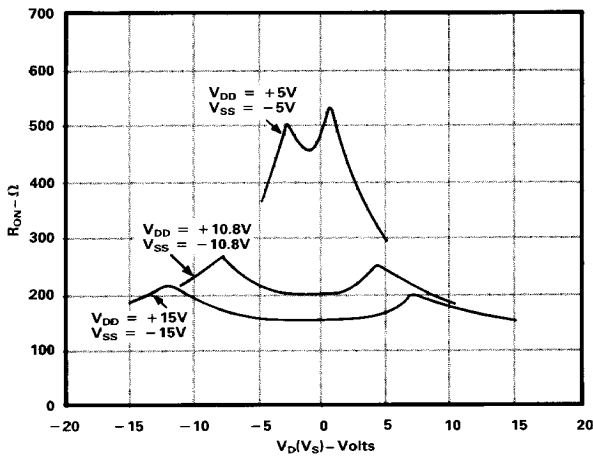


PLCC

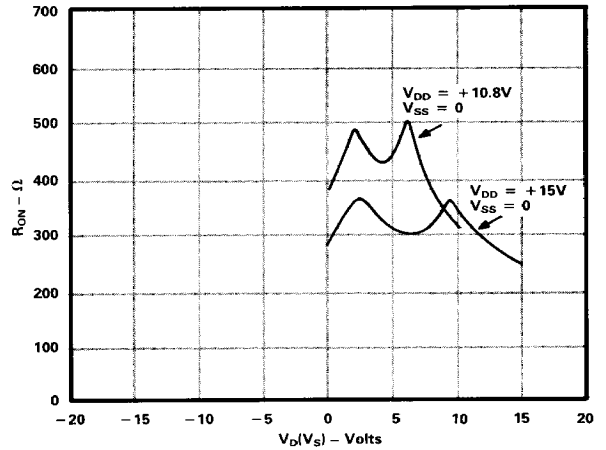


Typical Performance Characteristics

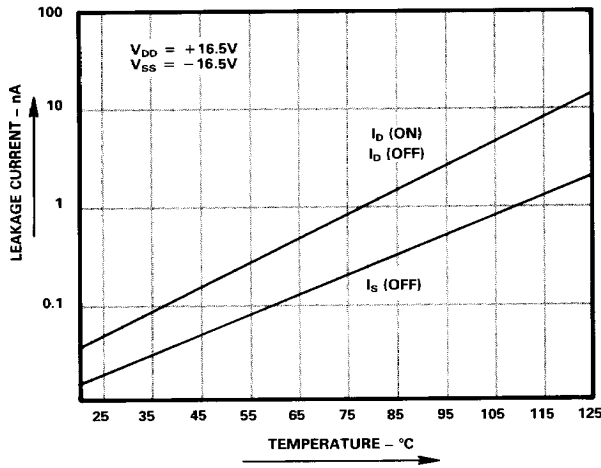
The multiplexers are guaranteed functional with reduced single or dual supplies down to 4.5V.



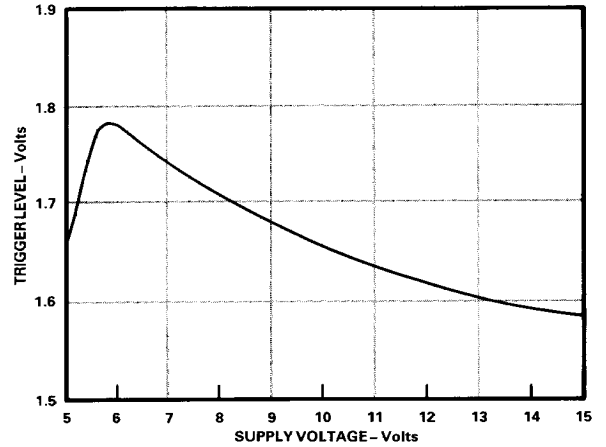
R_{ON} as a Function of $V_D(V_S)$: Dual Supply Voltage, $T_A = +25^\circ\text{C}$



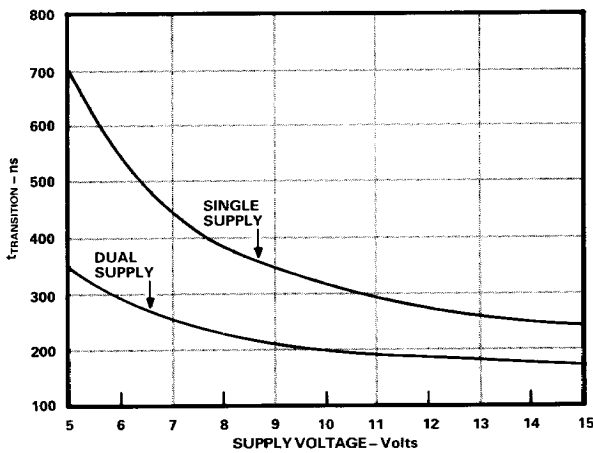
R_{ON} as a Function of $V_D(V_S)$: Single Supply Voltage, $T_A = +25^\circ\text{C}$



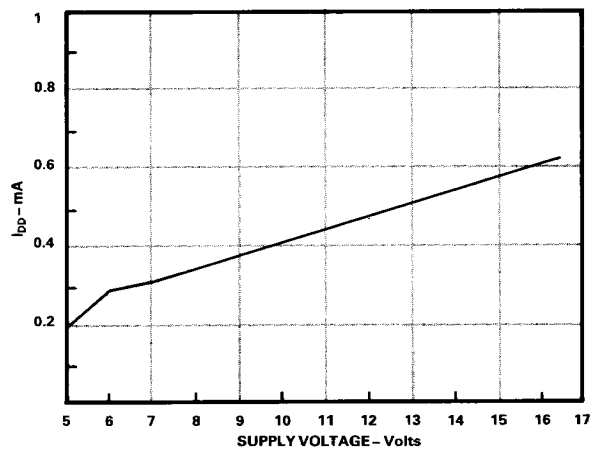
Leakage Current as a Function of Temperature (Note: Leakage Currents Reduce as the Supply Voltages Reduce)



Trigger Levels vs. Power Supply Voltage, Dual or Single Supply, $T_A = +25^\circ\text{C}$



$t_{TRANSITION}$ vs. Supply Voltage: Dual and Single Supplies, $T_A = +25^\circ\text{C}$
(Note: For V_{DD} and $|V_{SS}| < 10\text{V}$; $V_1 = V_{DD}/V_{SS}$, $V_2 = V_{SS}/V_{DD}$. See Test Circuit 6)

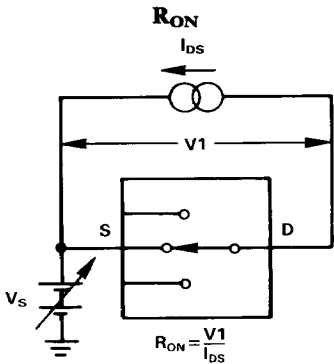


I_{DD} vs. Supply Voltage: Dual or Single Supply, $T_A = +25^\circ\text{C}$

Test Circuits

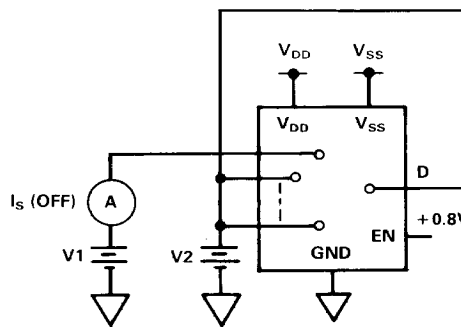
Note: All Digital Input Signal Rise and Fall Times Measured from 10% to 90% of 3V. $t_R = t_F = 20ns$.

TEST CIRCUIT 1



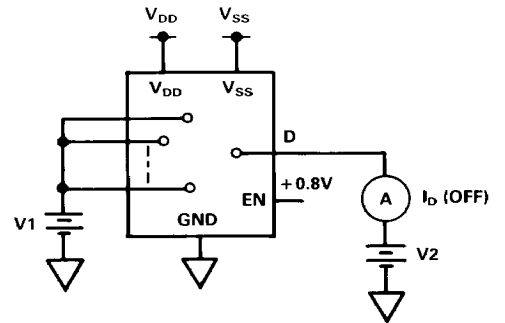
TEST CIRCUIT 2

I_S (OFF)



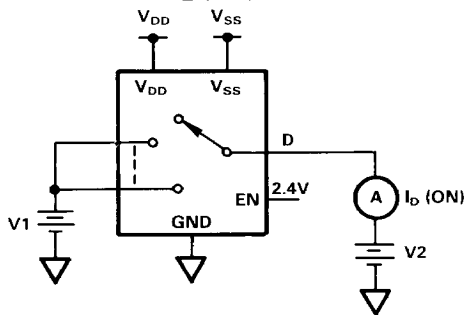
TEST CIRCUIT 3

I_D (OFF)



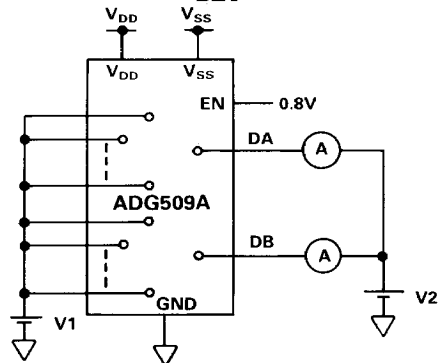
TEST CIRCUIT 4

I_D (ON)



TEST CIRCUIT 5

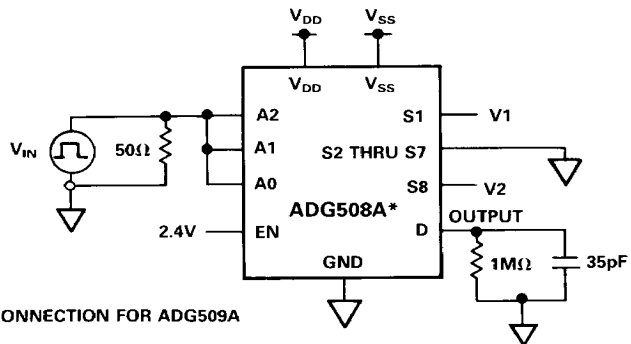
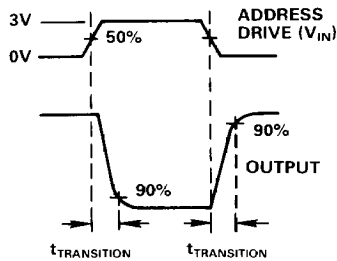
I_{DIFF}



$I_{DIFF} = I_{DA} (OFF) - I_{DB} (OFF)$

TEST CIRCUIT 6

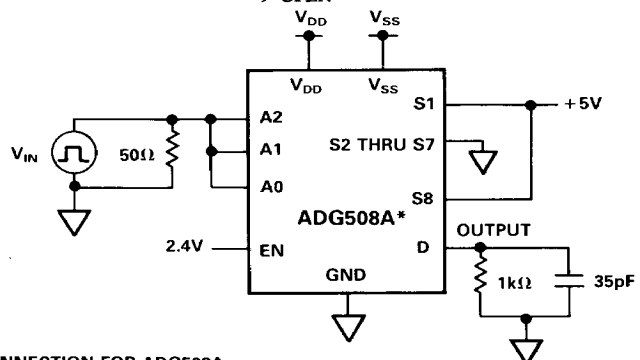
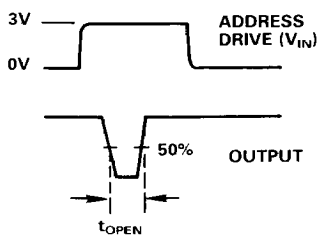
SWITCHING TIME OF MULTIPLEXER, $t_{TRANSITION}$



*SIMILAR CONNECTION FOR ADG509A

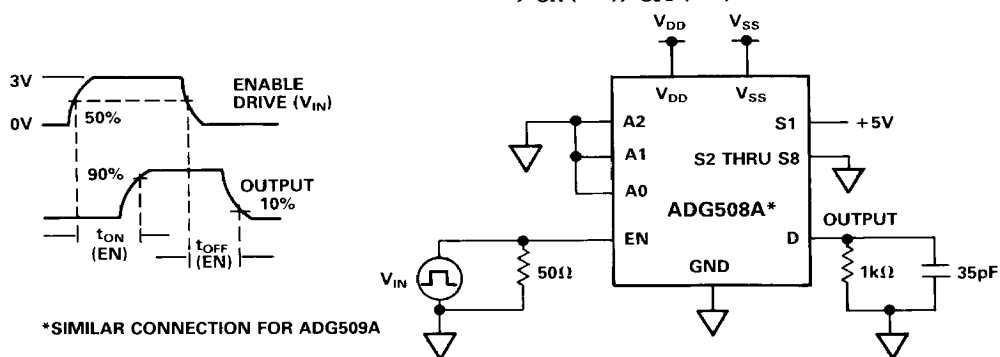
TEST CIRCUIT 7

BREAK-BEFORE-MAKE DELAY, t_{OPEN}

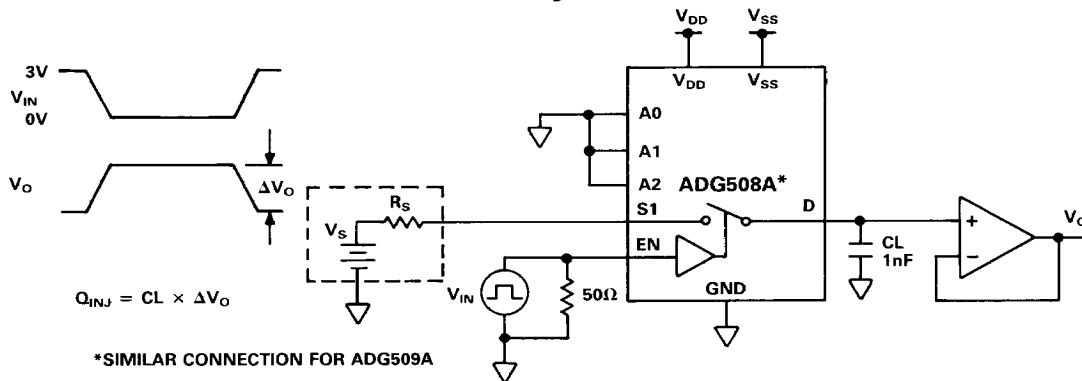


*SIMILAR CONNECTION FOR ADG509A

TEST CIRCUIT 8
ENABLE DELAY, $t_{ON}(EN)$, $t_{OFF}(EN)$



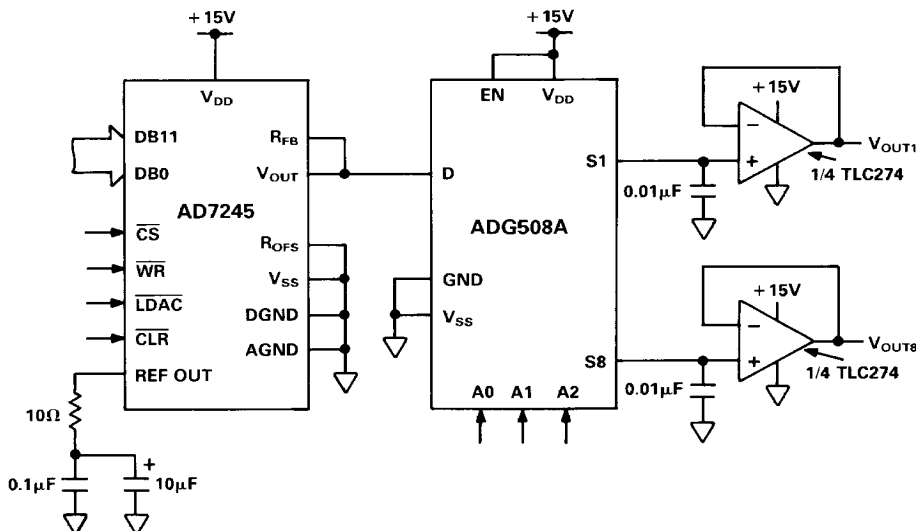
TEST CIRCUIT 9
CHARGE INJECTION



SINGLE SUPPLY OCTAL DAC APPLICATION

The following circuit shows the ADG508A connected as a demultiplexer to provide eight separate digitally programmable voltages (0 to +10V) from the AD7245. The AD7245 is a complete 12-bit, voltage output DAC with output amplifier and Zener

voltage reference on a monolithic CMOS chip. The entire system operates from a single +15V power supply. The ADG508A is ideally suited for the application because it has both low charge injection and I_S (OFF) leakage current.



ADG508A in a Single-Supply Octal DAC Circuit

TERMINOLOGY

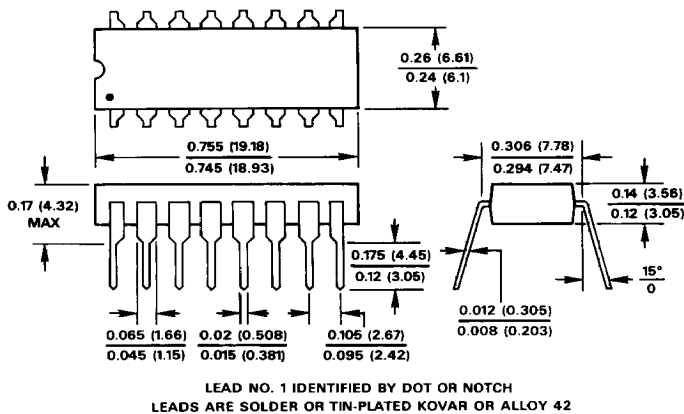
R_{ON}	Ohmic resistance between terminals D and S
R_{ON} Match	Difference between the R_{ON} of any two channels
R_{ON} Drift	Change in R_{ON} versus temperature
I_S (OFF)	Source terminal leakage current when the switch is off
I_D (OFF)	Drain terminal leakage current when the switch is off
I_D (ON)	Leakage current that flows from the closed switch into the body
V_S (V_D)	Analog voltage on terminal S or D
C_S (OFF)	Channel input capacitance for "OFF" condition
C_D (OFF)	Channel output capacitance for "OFF" condition
C_{IN}	Digital input capacitance
t_{ON} (EN)	Delay time between the 50% and 90% points of the digital input and switch "ON" condition

t_{OFF} (EN)	Delay time between the 50% and 10% points of the digital input and switch "OFF" condition
$t_{TRANSITION}$	Delay time between the 50% and 90% points of the digital inputs and switch "ON" condition when switching from one address state to another
t_{OPEN}	"OFF" time measured between 50% points of both switches when switching from one address state to another
V_{INL}	Maximum input voltage for Logic "0"
V_{INH}	Minimum input voltage for Logic "1"
I_{INL} (I_{INH})	Input current of the digital input
V_{DD}	Most positive voltage supply
V_{SS}	Most negative voltage supply
I_{DD}	Positive supply current
I_{SS}	Negative supply current

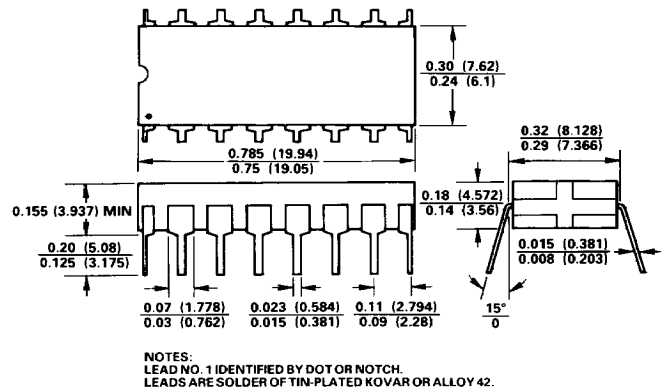
**MECHANICAL INFORMATION
OUTLINE DIMENSIONS**

Dimensions shown in inches and (mm).

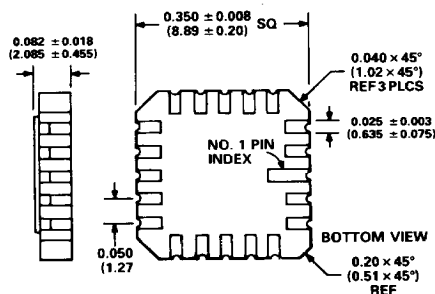
16-PIN PLASTIC DIP (SUFFIX N)



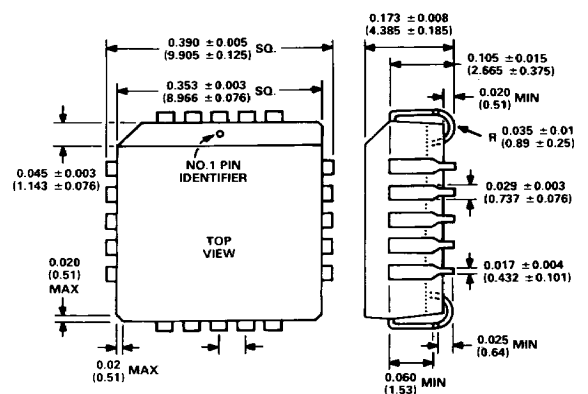
16-PIN CERDIP (SUFFIX Q)



20-TERMINAL LEADLESS CERAMIC CHIP CARRIER (SUFFIX E)



20-TERMINAL PLASTIC LEADED CHIP CARRIER (SUFFIX P)



021478 R